NCV97311MW50AGEVB

NCV97311A Evaluation Board User's Manual

ON Semiconductor®

www.onsemi.com

EVAL BOARD USER'S MANUAL

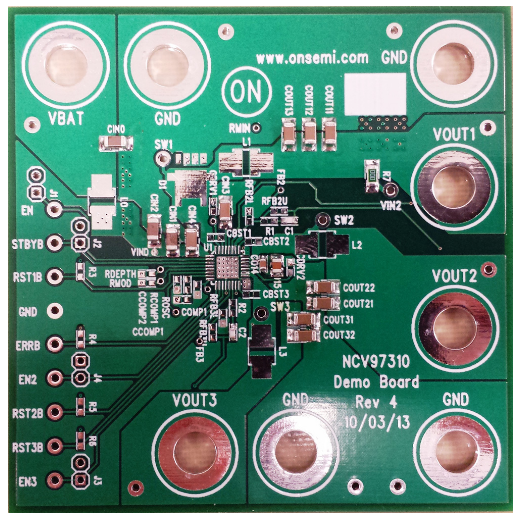


Figure 1. Evaluation Board Photo

Description

The NCV97311A is 3−output regulator consisting of a low−Iq battery−connected 3 A 2 MHz non−synchronous switcher and two low−voltage 1.5 A 2 MHz synchronous switchers; all using integrated power transistors.

The high−voltage switcher is capable of converting a 4.1 V to 18 V battery input to a 5 V output at a constant 2 MHz switching frequency, delivering up to 3 A. In overvoltage conditions up to 36 V, the switching frequency folds back to 1 MHz; in load dump conditions up to 45 V the regulator shuts down.

The output of the battery−connected buck regulator serves as the low voltage input for the 2 synchronous switchers. Each downstream output is adjustable from 1.2 V to 3.3 V, with a 1.5 A current limit and a constant 2 MHz switching frequency. Each switcher has independent enable and reset pins, giving extra power management flexibility.

For low−Iq operating mode the low−voltage switchers are disabled, and the standby rail is supplied by a low−Iq LDO (up to 150 mA) with a typical Iq of 30 μA. The LDO regulator is in parallel to the high−voltage switcher, and is activated when the switcher is forced in standby mode.

All 3 SMPS outputs use peak current mode control with internal slope compensation, internally−set soft−start, battery undervoltage lockout, battery overvoltage protection, cycle−by−cycle current limiting, hiccup mode short−circuit protection and thermal shutdown. An error flag is available for diagnostics.

Key Features

- Low Quiescent Current in Standby Mode
- 2 Microcontroller Enabled Low Voltage Synchronous Buck Converters
- Large Conversion Ratio of 18 V to 3.3 V Battery Connected Switcher
- Wide Input of 4.1 to 45 V with Undervoltage Lockout (UVLO)
- Fixed Frequency Operation Adjustable from 2.0 to 2.6 MHz
- Internal 1.5 ms Soft−starts
- Cycle−by−cycle Current Limit Protections
- Hiccup Overcurrent Protections (OCP)
- Individual Reset Pins with Adjustable Delays
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Infotainment, Body Electronics, Telematics, ECU

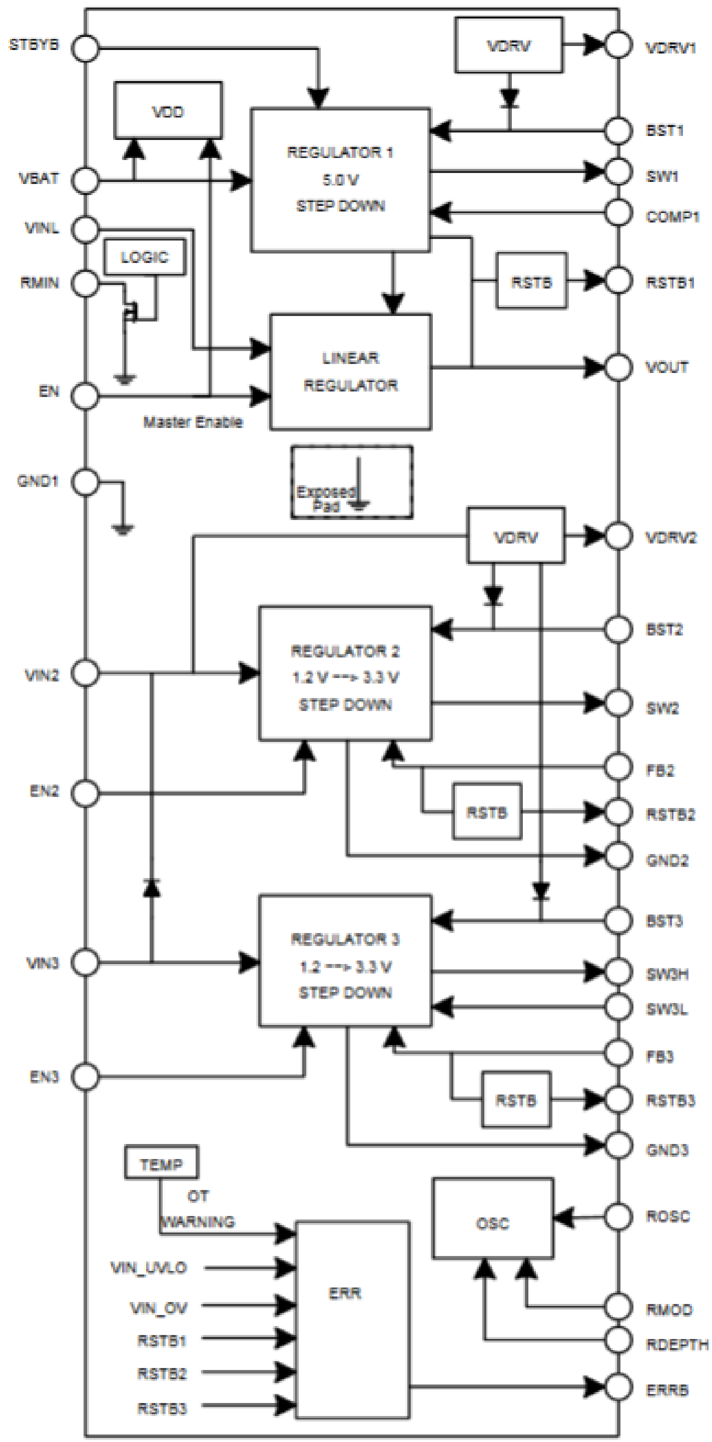


Figure 2. NCV9731150A Block Diagram

TYPICAL APPLICATION

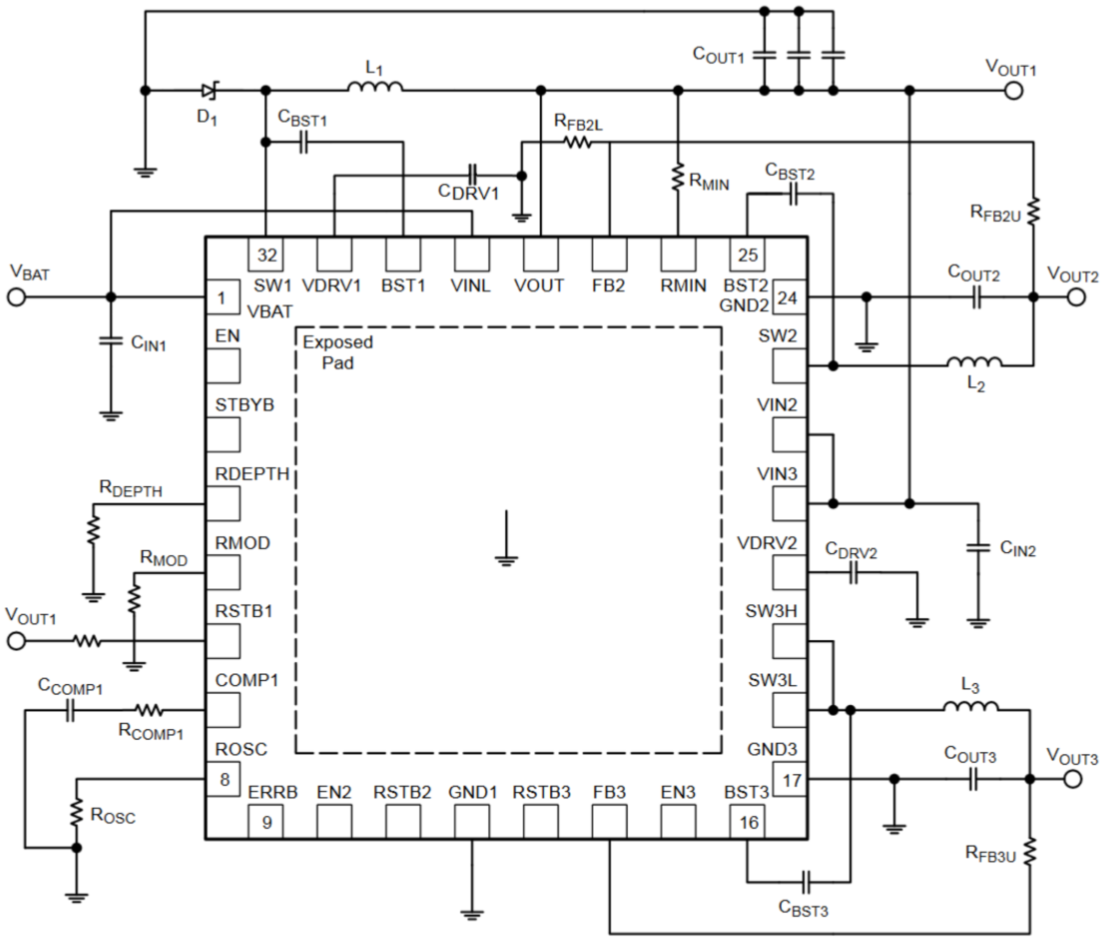


Figure 3. Typical Application

Table 1. EVALUATION BOARD TERMINALS

Pin Name	Function
VBAT	Positive dc input voltage
GND	Common dc return
VOUT1	Positive 5.0 V dc output voltage (LDO / switcher 1)
VOUT2	Positive DC output voltage (switcher 2)
VOUT3	Positive DC output voltage (switcher 3)
EN	Master enable input. Includes jumper J3 to connect to VBAT
STBYB	Standby enable input. Includes jumper J4 to connect to VBAT
EN2	Switcher 2 enable input. Includes jumper J6 to connect to VOUT1
EN3	Switcher 3 enable input. Includes jumper J5 to connect to VOUT1
ERRB	Error flag combining temperature and input and output voltage sensing
RST1B	Reset with adjustable delay. Goes low when the VOUT1 is out of regulation
RST2B	Reset with adjustable delay. Goes low when the VOUT2 is out of regulation
RST3B	Reset with adjustable delay. Goes low when the VOUT3 is out of regulation

Table 2. ABSOLUTE MAXIMUM RATINGS (Voltages are with respect to GND)

Rating	Value	Unit
Dc Supply Voltage (VBAT, EN, STBYB)	−0.3 to 36	V
Dc Supply Voltage (VIN2, VIN3)	−0.3 to 12	V
Dc Supply Voltage (RSTB1, RSTB2, RSTB3, ERRB, EN2, EN3)	−0.3 to 6	V
Storage Temperature Range	−55 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 3. ELECTRICAL CHARACTERSITICS (T_A = 25°C, 4.5 ≤ VIN ≤ 18 V, IOUT ≤ 2 A, unless otherwise specified)

Characteristic	Conditions	Typical Value	Unit
REGULATION			
Output Voltage (VOUT1)		5.0	V
Output Voltage (VOUT2)		3.3	V
Output Voltage (VOUT3)		1.2	V
Line Regulation (VOUT1)	I_{OUT1} = 1.0 A	0.03	%
Line Regulation (VOUT2)	I_{OUT2} = 1.0 A	0.01	%
Line Regulation (VOUT3)	I_{OUT3} = 1.0 A	0.001	%
Load Regulation (VOUT1)	V_{BAT} = 13.2 V	0.3	%
Load Regulation (VOUT2)	V_{BAT} = 13.2 V	0.02	%
Load Regulation (VOUT3)	V_{BAT} = 13.2 V	0.03	%
SWITCHING			
Switching Frequency		2.0	MHz
Soft−start Time		1.4	ms
R_{OSC} Frequency Range	50 kΩ ≥ R_{OSC} ≥ 10 kΩ	2.0 to 2.6	MHz
CURRENT LIMIT			
Peak Current Limit (VOUT1)	STBYB = 0 V	0.2	A
Peak Current Limit (VOUT1)	STBYB = 5 V	4.4	A
Peak Current Limit (VOUT2)		2.9	A
Peak Current Limit (VOUT3)		2.9	A
PROTECTION			
Input Undervoltage Lockout (UVLO)	V_{BAT} Decreasing	3.9	V
Input Overvoltage Protection	V_{BAT} Increasing	36	V
Thermal Warning	T_J Rising	150	°C
Thermal Shutdown	T_J Rising	170	°C

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

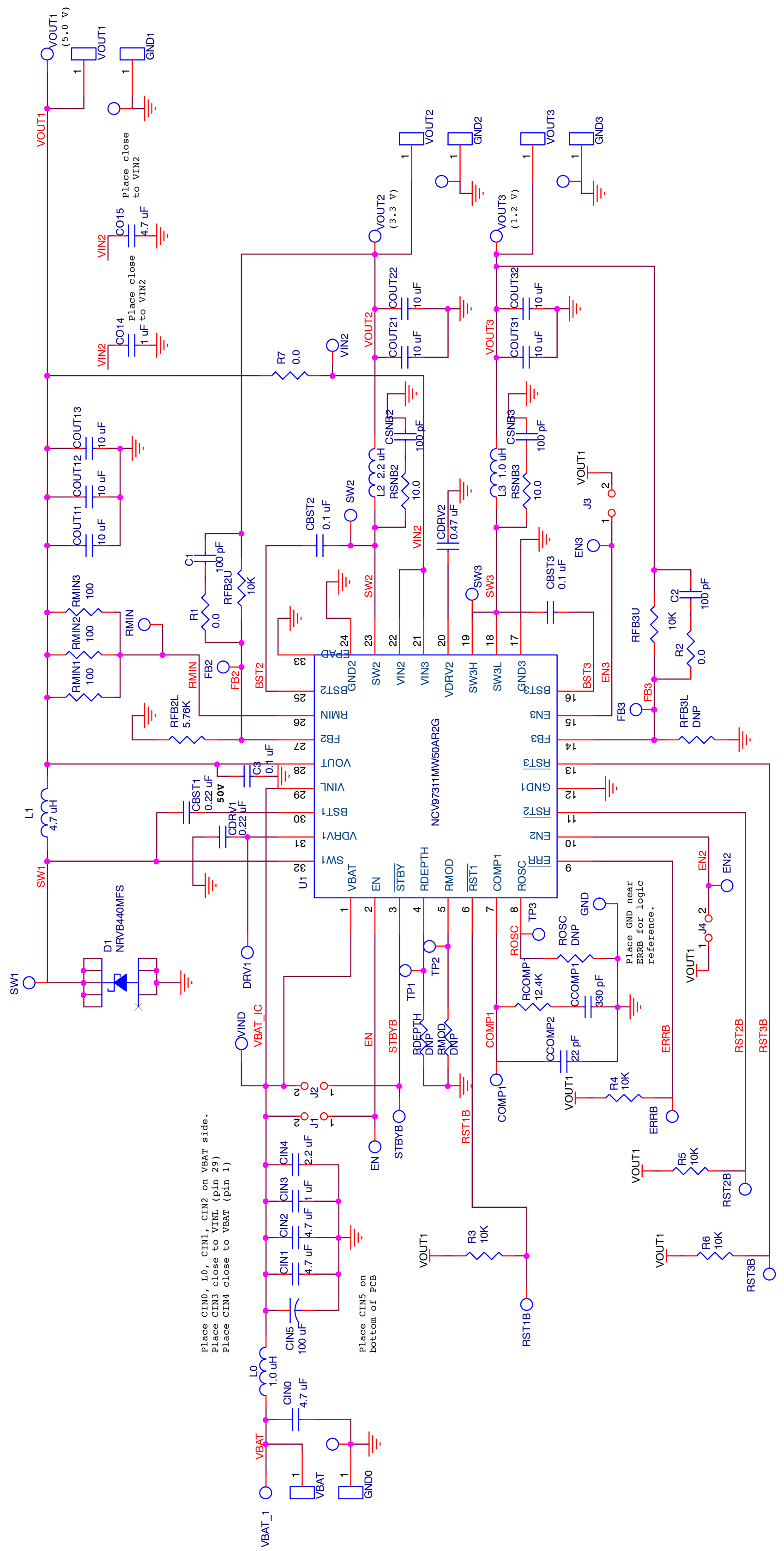


Figure 4. NCV97311AGEVB 5.0 V Board Schematic

Operational Guidelines

1. Connect a dc input voltage, within the 6.0 V to 36 V range, between VBAT and GND.
2. Connect a load (< 150 mA) between VOUT1 and GND
3. Connect a dc enable voltage, within the 2.0 V to 36 V range, between EN and GND. This will enable the internal LDO for low Iq mode. You may use jumper J1 to connect EN directly to VBAT.
   a. The VOUT1 signal should be 5.0 V.
   b. The VOUT2 signal should be disabled (regardless of EN2 state) and read 0 V.
   c. The VOUT3 signal should be disabled (regardless of EN3 state) and read 0 V.
4. Connect a dc enable voltage, within the 2.0 V to 36 V range, between STBYB and GND. This will exit low Iq mode and power up switcher 1. You may use jumper J2 to connect STBYB directly to VBAT.
   The VOUT1 signal should still be 5.0 V. You may now add a higher load to VOUT1.
5. Connect a dc enable voltage, within the 2.0 V to 6 V range, between EN2 and GND. This will power up switcher 2. You may use jumper J4 to connect EN2 directly to VOUT1.
   The VOUT2 signal should be 3.3 V.
6. Connect a dc enable voltage, within the 2.0 V to 6 V range, between EN3 and GND. This will power up switcher 3. You may use jumper J3 to connect EN3 directly to VOUT1.
   The VOUT3 signal should be 1.2 V.

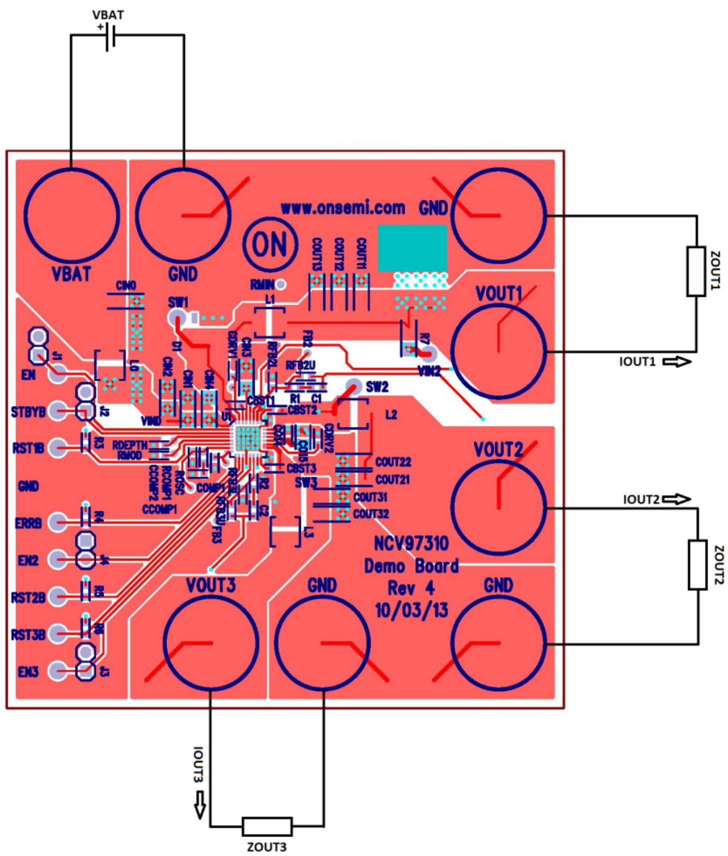
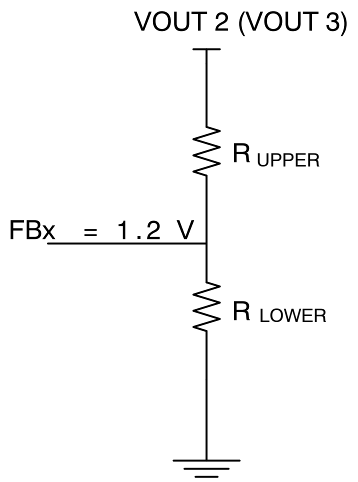


Figure 5. NCV97311A Board Connections

APPLICATION INFORMATION

Output Voltage Selection

The voltage outputs for switcher 2 and switcher 3 are adjustable and can be set with a resistor divider. The FB reference for both switchers is 1.2 V.



The upper resistor is set to 10 kΩ and is part of the feedback loop. To maintain stability over all conditions, it is recommended to change the only the lower feedback resistor to set the output voltage. Use the following equation:

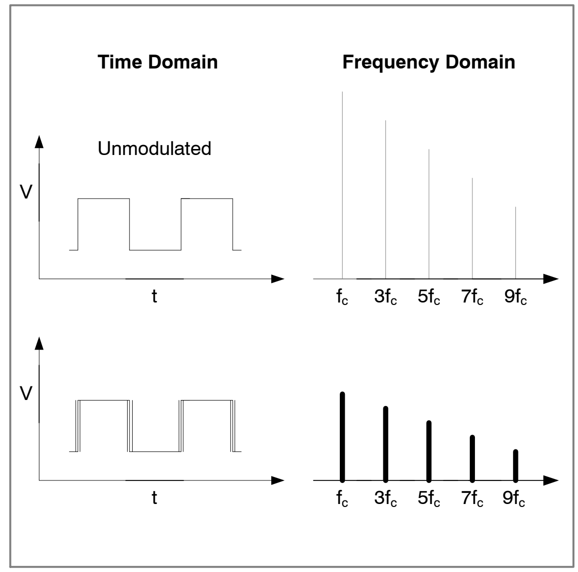
$$R_{LOWER} = R_{UPPER} \frac{V_{FB}}{V_{OUT} - V_{FB}}$$

Some common setups are listed below:

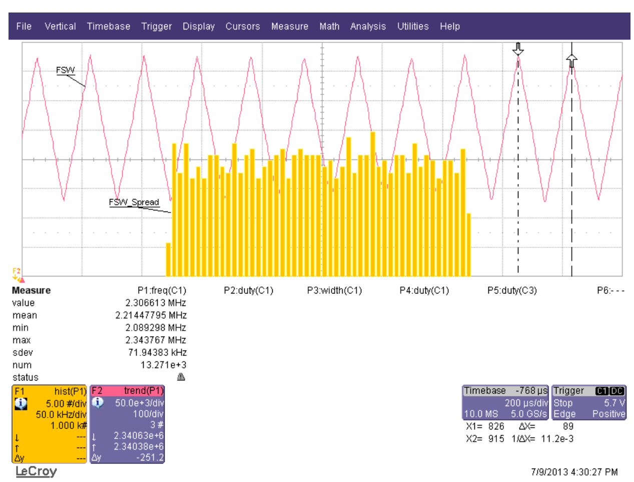
Desired Output (V)	VREF (V)	R_{UPPER} (kΩ, 1%)	R_{LOWER} (kΩ, 1%)
1.2	1.2	10.0	NP
1.5	1.2	10.0	40.0
1.8	1.2	10.0	20.0
2.5	1.2	10.0	9.31
3.3	1.2	10.0	5.76

Spread Spectrum

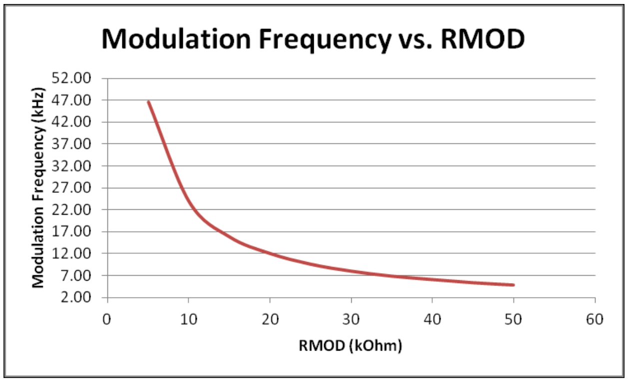
In SMPS devices, switching translates to higher efficiency. Unfortunately, the switching leads to a much noisier EMI profile. We can greatly decrease some of the radiated emissions with some spread spectrum techniques. Spread spectrum is used to reduce the peak electromagnetic emissions of a switching regulator.

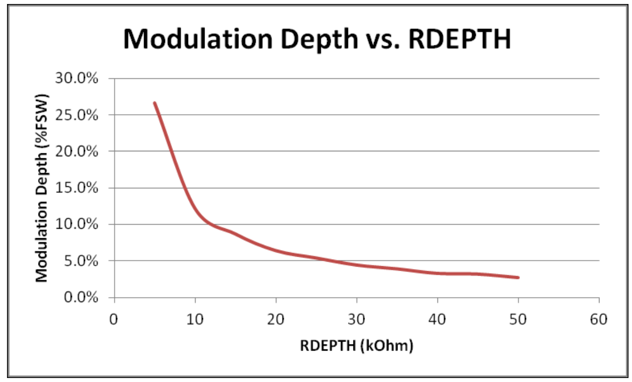


The spread spectrum used in the NCV97311A is an “up−spread” technique, meaning the switching frequency is spread upward from the 2.0 MHz base frequency. For example, a 5 % spread means that the switching frequency is swept (spread) from 2.0 MHz up to 2.1 MHz in a linear fashion – this is called the modulation depth. The rate at which this spread takes place is called the modulation frequency. For example, a 10 kHz modulation frequency means that the frequency is swept from 2.0 MHz to 2.1 MHz in 50 μs and then back down from 2.1 MHz to 2.0 MHz in 50 μs.



The modulation depth and modulation frequency are each set by 2 external resistors to GND. The modulation frequency can be set from 5 kHz up to 50 kHz using a resistor from the RMOD pin to GND. The modulation depth can be set from 3% up to 30% of the nominal switching frequency using a resistor from the RDEPTH pin to GND. Please see the curves below for typical values:





Spread spectrum is automatically turned off when there is a short to GND or an open circuit on either the RMOD pin or the RDEPTH pin. Please be sure that the ROSC pin is an open circuit when using spread spectrum.

TYPICAL PERFORMANCE

Efficiency

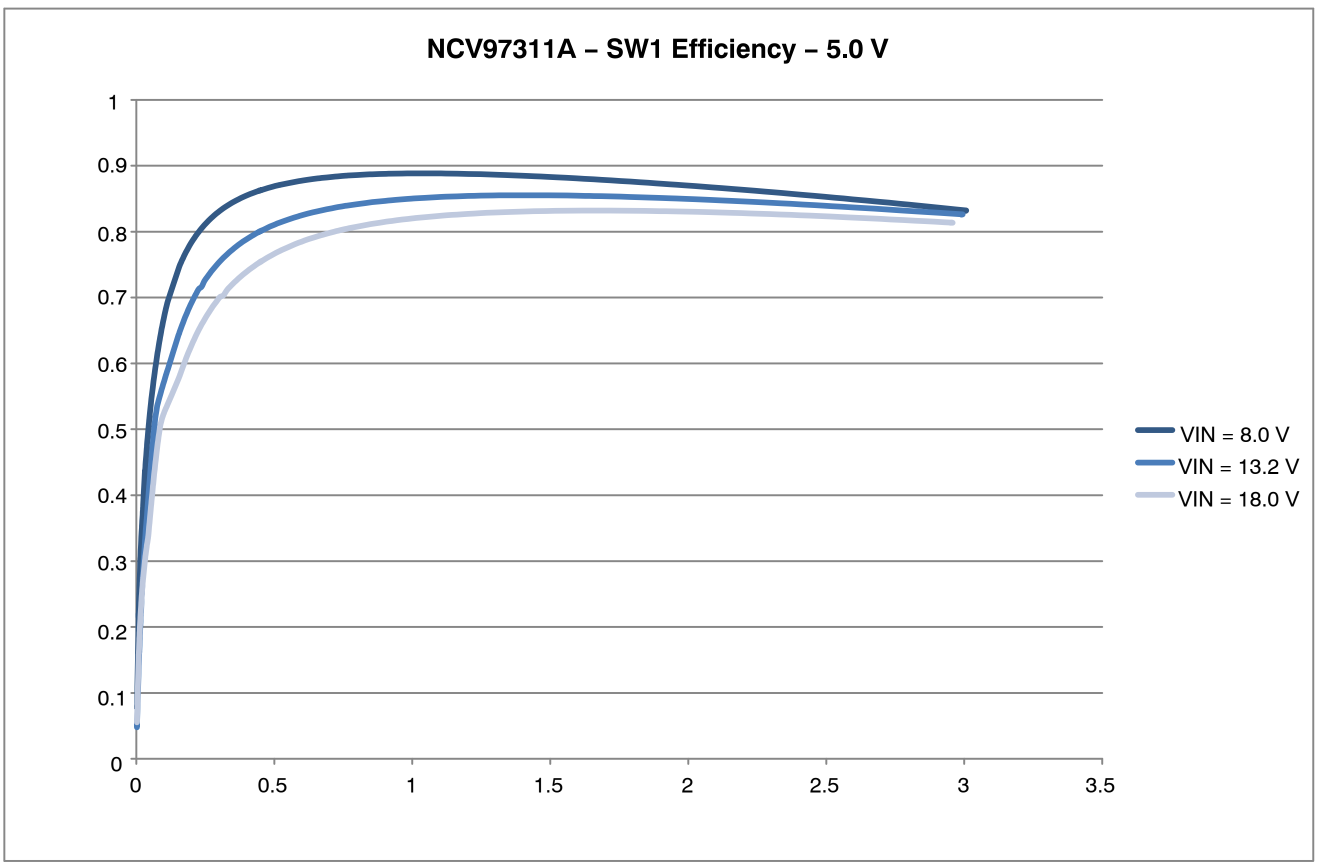


Figure 6. Efficiency for SW1 with a 5.0 V Output

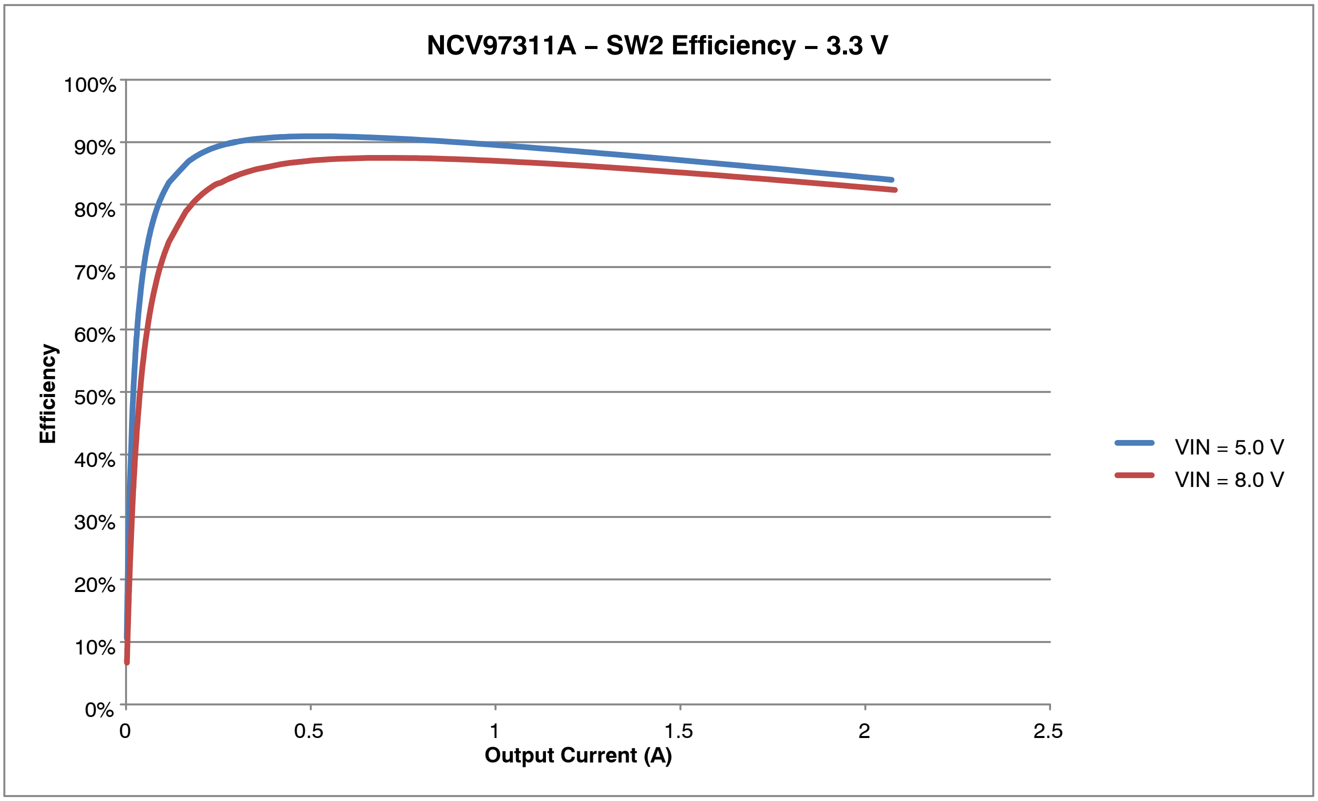


Figure 7. Efficiency for SW2 with a 3.3 V Output

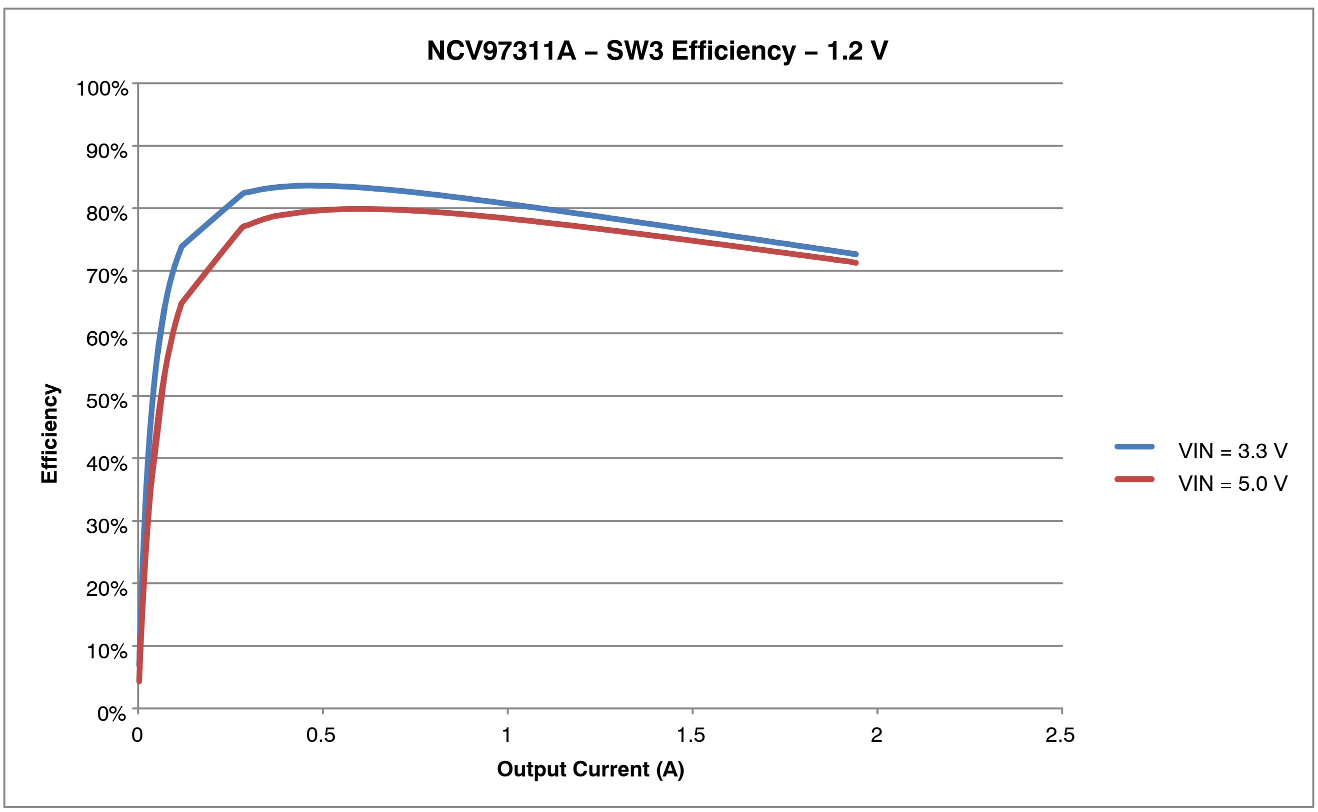


Figure 8. Efficiency for SW3 with a 1.2 V Output

Line Regulation

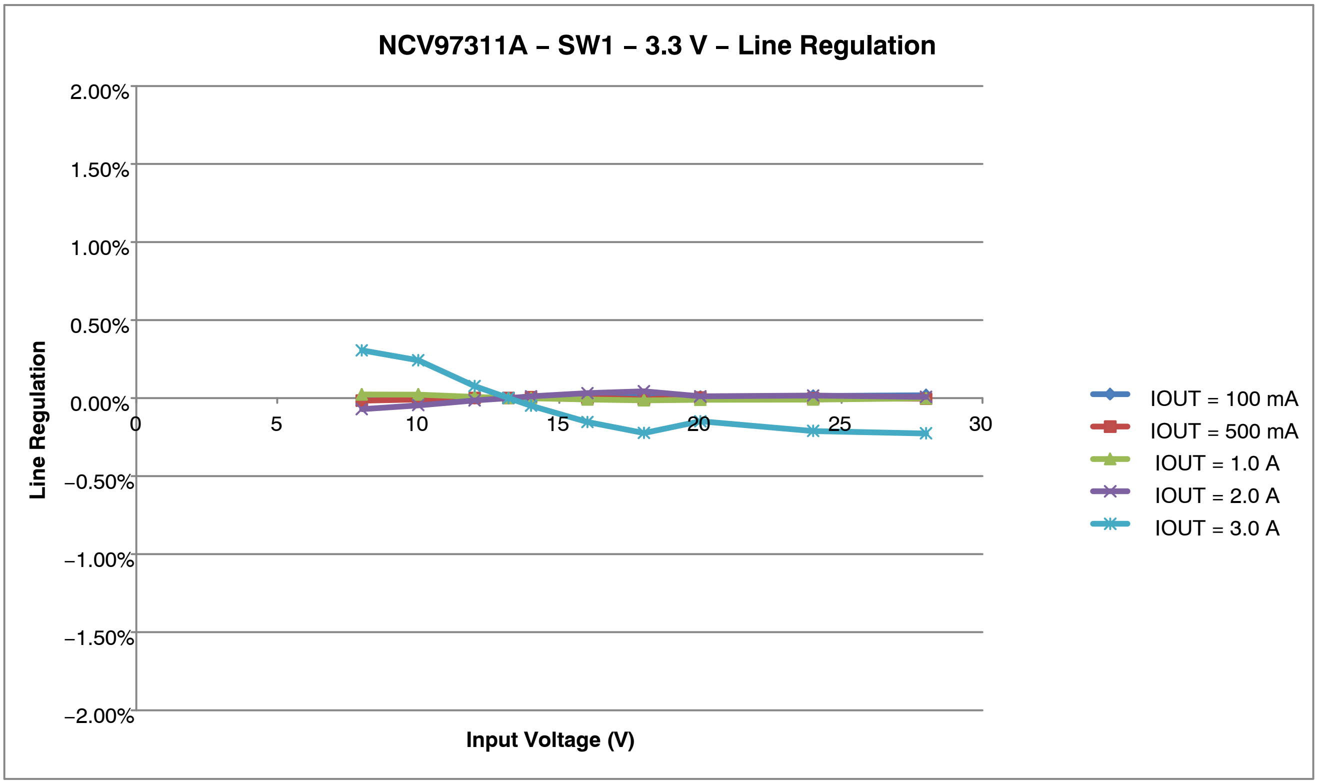


Figure 9. Line Regulation for SW1 with a 3.3 V Output

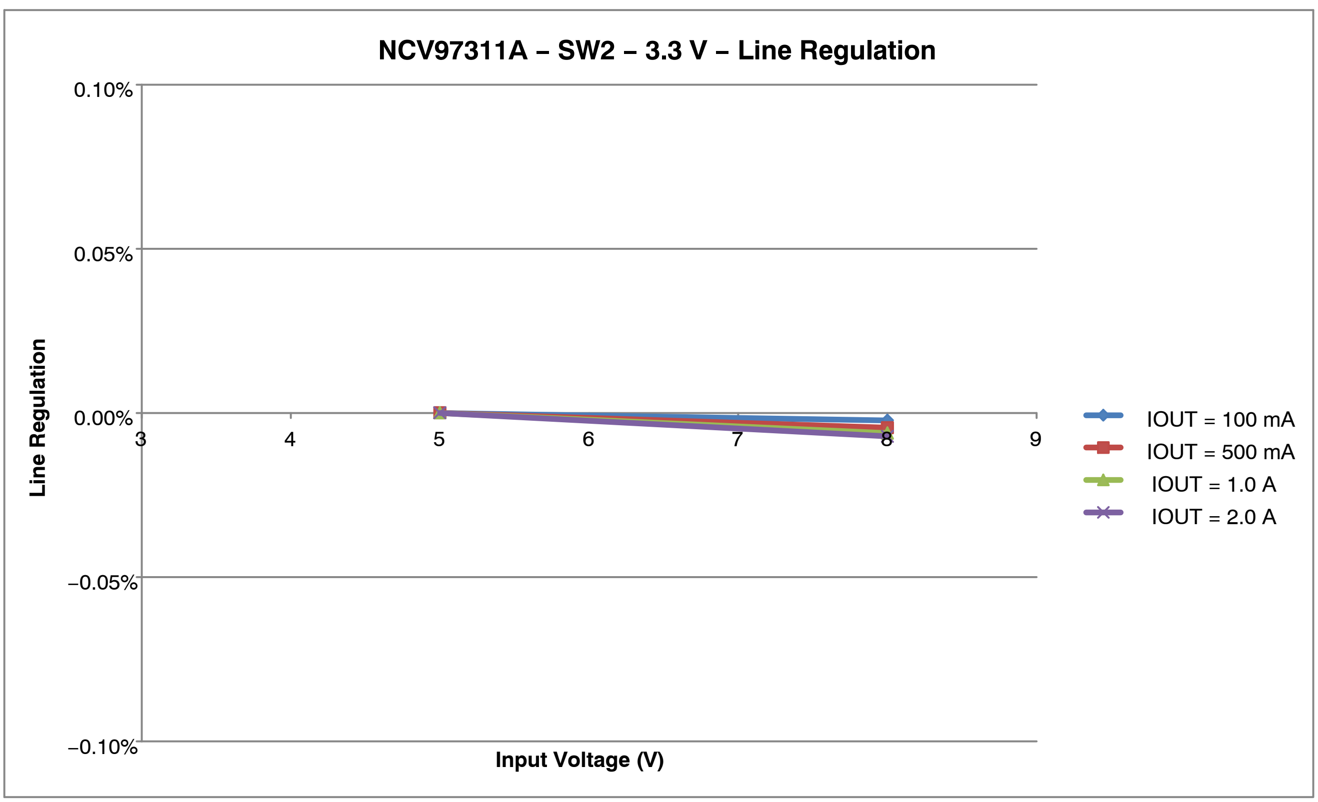


Figure 10. Line Regulation for SW2 with a 3.3 V Output

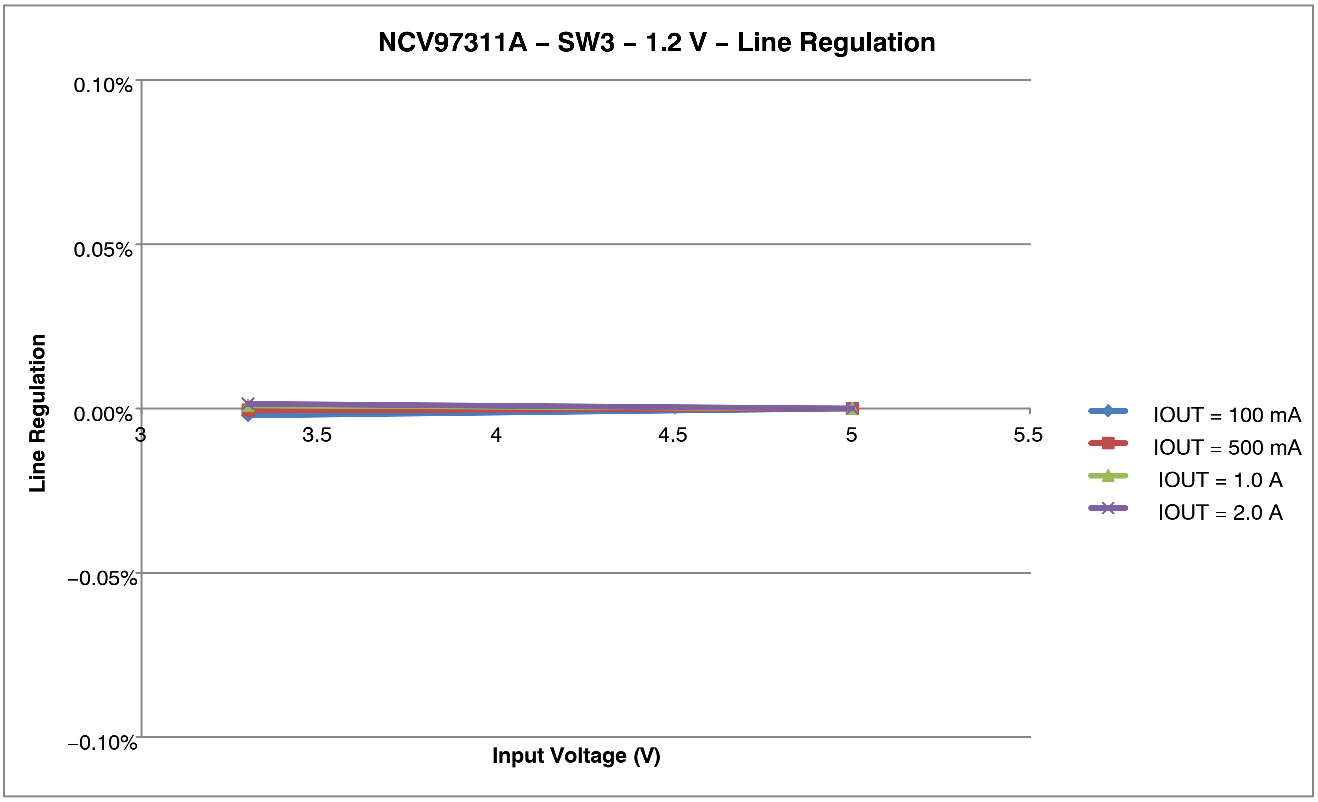


Figure 11. Line Regulation for SW3 with a 1.2 V Output

Load Regulation

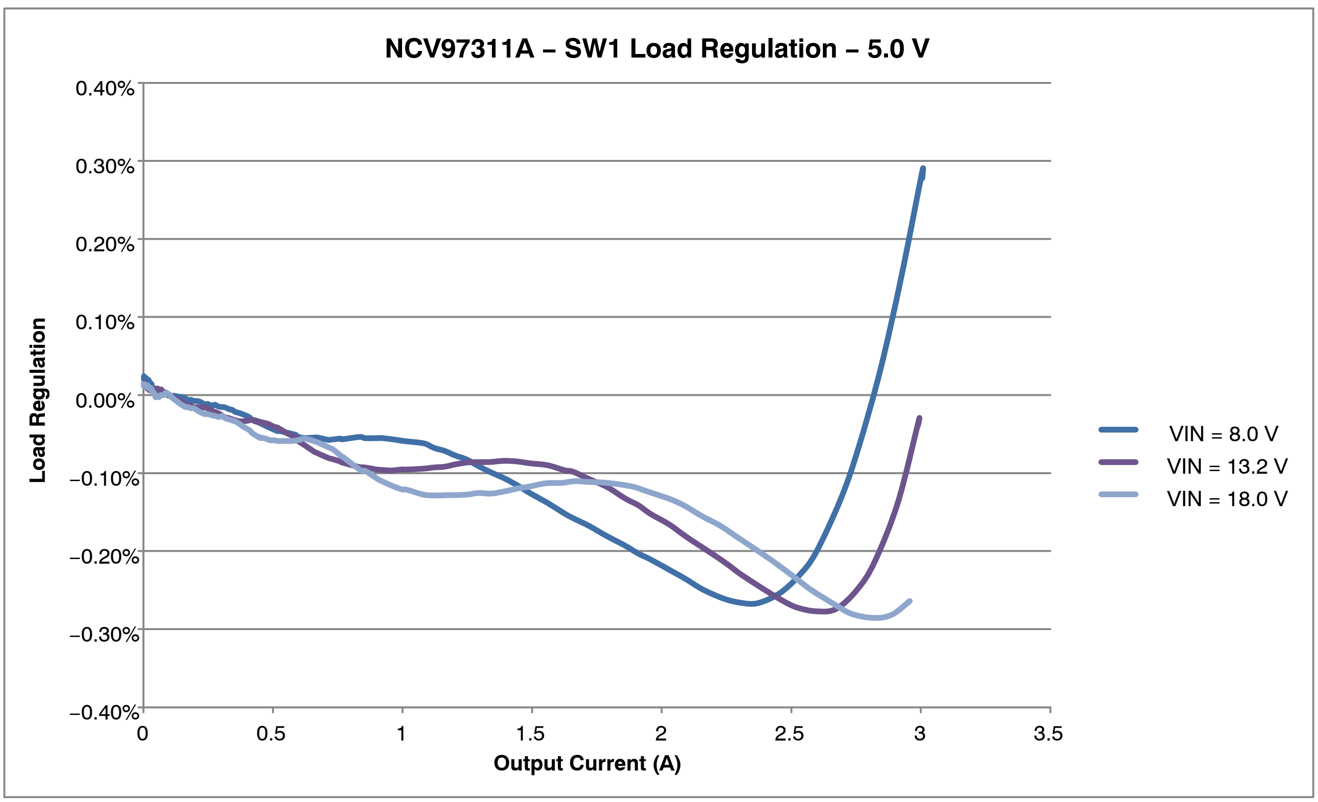


Figure 12. Load Regulation for SW1 with a 5.0 V Output

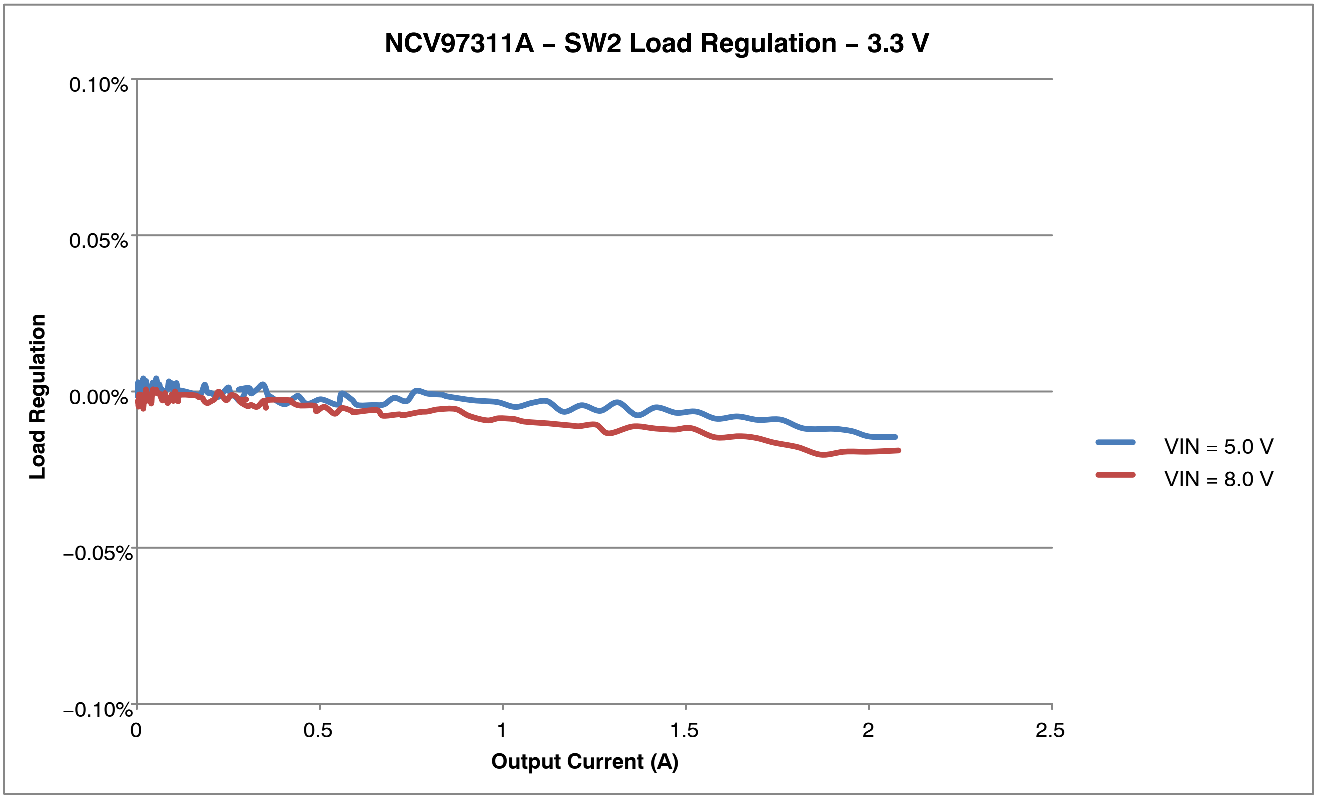


Figure 13. Load Regulation for SW2 with a 3.3 V Output

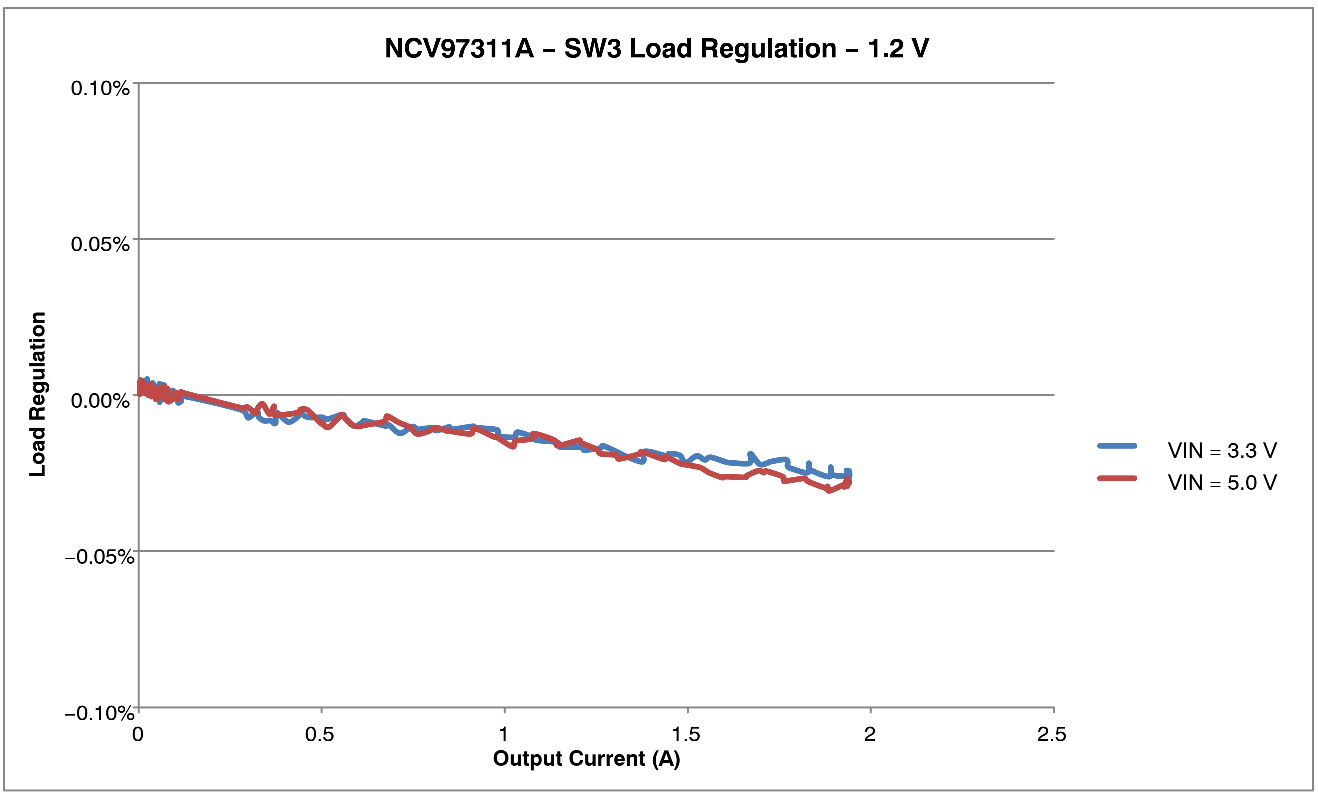
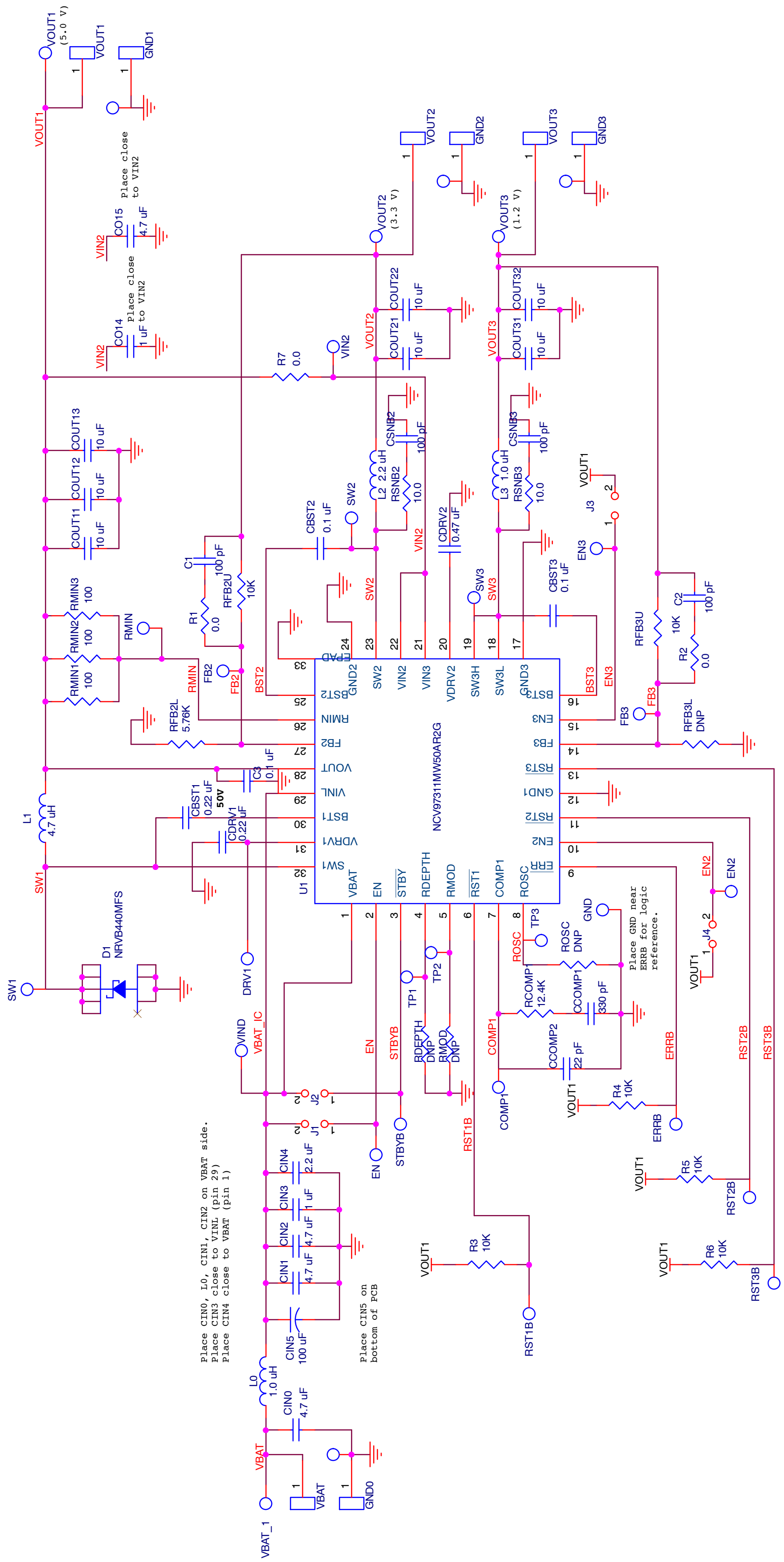


Figure 14. Load Regulation for SW3 with a 1.2 V Output

NCV97311MW50AGEVB

SCHEMATIC



PCB LAYOUT

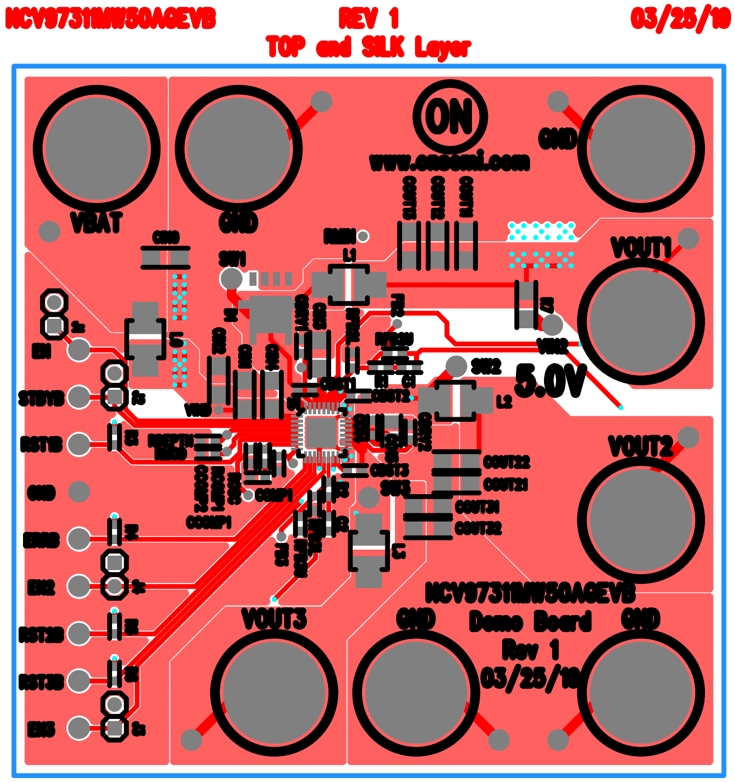


Figure 15. Top View

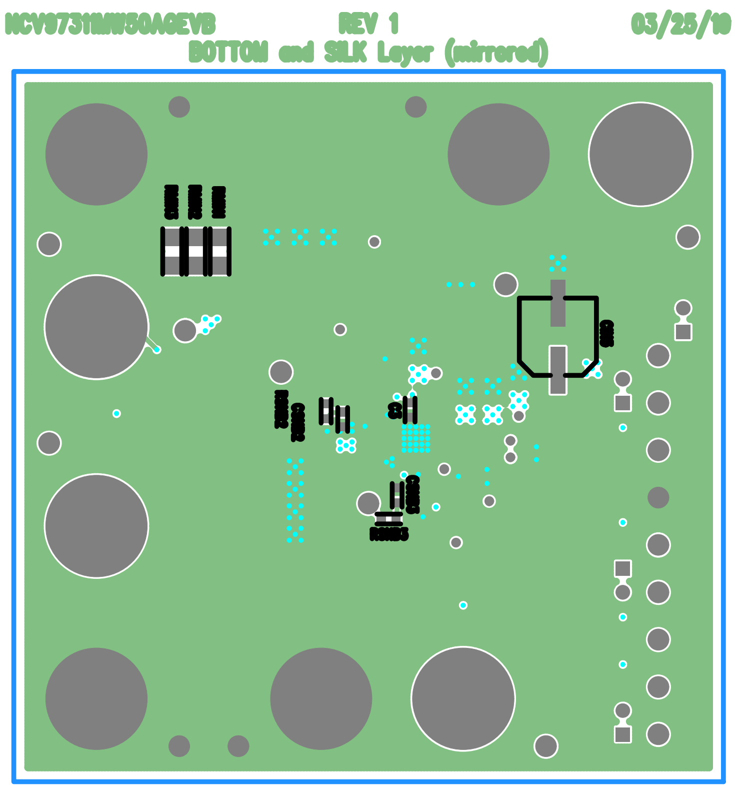


Figure 16. Bottom View

BILL OF MATERIALS

Table 4. BILL OF MATERIALS

Reference Designator(s)	Qty.	Description	Value	Tolerance	Footprint	Manufacturer	Manufacturer's Part Number	Substi-tution Allowed
C1, C2, CSNB2, CSNB3	4	CAP CER 100 pF 50 V 5% NP0 0603	100 pF	5%	603	Murata Electronics North America	GCM1885C1H101JA16D	Yes
C3, CBST1, CBST2, CBST3, CDRV1	3	CAP CER 0.1 μF 50 V 10% X7R 0603	0.1 μF	10%	603	Murata Electronics North America	GCM188R71H104KA57D	Yes
CBST1, CDRV1	2	CAP CER 0.22 μF 50 V 10% X7R 0603	0.22 μF	10%	603	Murata Electronics North America	GCM188R71H224KA64D	Yes
CCOMP1	1	CAP CER 330 pF 50 V 5% NP0 0603	330 pF	5%	603	Murata Electronics North America	GCM1885C1H331JA16D	Yes
CCOMP2	1	CAP CER 22 pF 50 V 5% NP0 0603	22 pF	5%	603	Murata Electronics North America	GCM1885C1H220JA16D	Yes
CDRV2	1	CAP CER 0.47 μF 16 V 10% X7R 0603	0.47 μF	10%	603	Murata Electronics North America	GCM188R71C474KA55D	Yes
CIN0, CIN1, CIN2	3	CAP CER 4.7 μF 50 V 10% X7R 1206	4.7 μF	10%	1206	TDK Corporation	C3216X7R1H475K160AC	Yes
CIN3	1	CAP CER 1.0 μF 50 V 10% X7R 1206	1.0 μF	10%	1206	Murata Electronics North America	GCM31MR71H105KA55L	Yes
CIN4	1	CAP CER 2.2 μF 50 V 10% X7R 1206	2.2 μF	10%	1206	Murata Electronics North America	GCM31CR71H225KA55L	Yes
CIN5	1	CAP ALUM 100 μF 50 V 20% SMD	100 μF	20%	FK_V_E	Chemi−Con	EMZA500ADA101MHA0G	Yes
CO14	1	CAP CER 1 μF 16 V 10% X7R 0603	1.0 μF	10%	603	Murata Electronics North America	GCM188R71C105KA64D	Yes
CO15	1	CAP CER 4.7 μF 16 V 10% X7R 0805	4.7 μF	10%	805	TDK Corporation	CGA4J3X7R1C475K125AB	Yes
COUT11, COUT12, COUT13, COUT21, COUT22, COUT31, COUT32	7	CAP CER 10 μF 10 V 10% X7R 1206	10 μF	10%	1206	Murata Electronics North America	GCM31CR71A106KA64L	Yes
R1, R2	2	RES 0.0 Ω 1/10 W 0603 SMD	0 Ω	Jumper	603	Vishay/Dale	CRCW06030000Z0EA	Yes
R3, R4, R5, R6, RFB2U, RFB3U	6	RES 10.0 kΩ 1/10 W 1% 0603 SMD	10.0 kΩ	1%	603	Vishay/Dale	CRCW060310K0FKEA	Yes
R7	1	RES 0.0 Ω 1/4 W 1206 SMD	0 Ω	Jumper	1206	Vishay/Dale	CRCW12060000Z0EA	Yes
RCOMP1	1	RES 12.4 kΩ 1/10 W 1% 0603 SMD	12.4 kΩ	1%	603	Vishay/Dale	CRCW060312K4FKEA	Yes
RFB2L	1	RES 5.76 kΩ 1/10 W 1% 0603 SMD	5.76 kΩ	1%	603	Vishay/Dale	CRCW06035K76FKEA	Yes
RMIN1, RMIN2, RMIN3	3	RES 100 Ω 1/4 W 1% 1206 SMD	100 Ω	1%	1206	Vishay/Dale	CRCW1206100RFKEA	Yes
RSNB2, RSNB3	2	RES 10.0 Ω 1/10 W 1% 0603 SMD	10.0 Ω	1%	603	Vishay/Dale	CRCW060310R0FKEA	Yes
D1	1	DIODE SCHOTTKY 4.0 A 40 V SMB	40 V/4.0 A	N/A	SMB_DIODE	ON Semiconductor	NRVB440MFST1G	No
L0, L3	2	High Current Shielded Inductor 1.0 μH, 8.7 A SAT	1.0 μH	20%	XAL4020−102ME	Coilcraft	XAL4020−102ME	No
L1	1	High Current Shielded Inductor 4.7 μH, 4.5 A SAT	4.7 μH	20%	XAL4030−472ME	Coilcraft	XAL4030−472ME	No
L2	1	High Current Shielded Inductor 2.2 μH, 5.6 A SAT	2.2 μH	20%	XAL4020−222ME	Coilcraft	XAL4020−222ME	No

Table 4. BILL OF MATERIALS (continued)

Reference Designator(s)	Qty.	Description	Value	Tolerance	Footprint	Manufacturer	Manufacturer's Part Number	Substi-tution Allowed
EN, EN2, EN3, ERRB, GNDL, PGND1_1, PGND1_2, PGND2_1, PGND3_1, RST1B, RST2B, RST3B, STBYB, SW1, SW2, SW3, VIN2, VBAT, VOUT1_1, VOUT2_1, VOUT3_1	21	PIN INBOARD .042″ HOLE 1000/PKG	N/A	N/A	TP	Vector Electronics	K24C/M	Yes
GND0, GND1, GND2, GND3, VBAT, VOUT1, VOUT2, VOUT3	8	CONN JACK BANANA UNINS PANEL MOU	N/A	N/A	BANANA	Emerson Network Power Connectivity Johnson	108−0740−001	No
J1, J2, J3, J4	4	CONN HEADER 2POS .100 VERT GOLD	N/A	N/A	JMP	Molex Connector Corporation	22−28−4023	Yes
	4	CONN JUMPER SHORTING GOLD	N/A	N/A	JMP	Sullins Connector Solutions	SSC02SYAN	Yes
COMP1, DRV1, FB2, FB3, RMIN, TP1, TP2, TP3, VIND	9	CIRCUIT PIN PRNTD .020″D .425″L	Do Not Populate	N/A	SMALLTP	Mill−Max Manufacturing Corp.	3128−2−00−15−00−00−08−0	Yes
RDEPTH, RFB3L, RMOD, ROSC	4		Do Not Populate		603			Yes
U1	1	Automotive Battery−Connected Low IQ Multi−Output PMU	N/A	N/A	QFN32	ON Semiconductor	NCV97311MW50AR2G	No

NOTE: All devices are RoHS Compliant.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Email Requests to: orderlit@onsemi.com

ON Semiconductor Website: www.onsemi.com

TECHNICAL SUPPORT
North American Technical Support:
Voice Mail: 1 800−282−9855 Toll Free USA/Canada
Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:
Phone: 00421 33 790 2910
For additional information, please contact your local Sales Representative